NSN 5961-01-340-6275 Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-340-6275
Inclosure Material:
Metal
Overall Length:
1.573 inches
Overall Height:
Between 0.250 inches and 0.360 inches
Overall Width:
1.050 inches
Function For Which Designed:
Switching
Mounting Facility Quantity:
2
Internal Configuration:
Field effect
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-204aa
Electrode Internally-electrically Connected To Case:
Drain
Mounting Method:
Unthreaded hole
Features Provided:
Quality assurance level tx and hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-200.0 drain to source voltage and -200.0 drain to gate voltage
Current Rating Per Characteristic:
-28.00 amperes off-state current, peak
Power Rating Per Characteristic:
4.0 watts total power dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 pin and 1 case
Specification Data:
81349-mil-s-19500/562 government specification
Shelf Life:
N/a

Unit Of Measure:

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